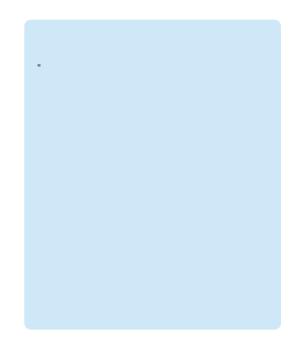
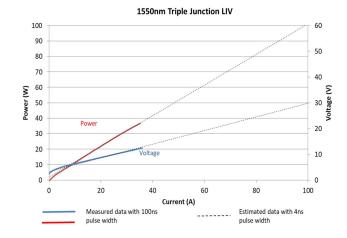
Preliminary Data Sheet









12/1/23, 7:16 AM

PI Sheet

Triple Junction TO56

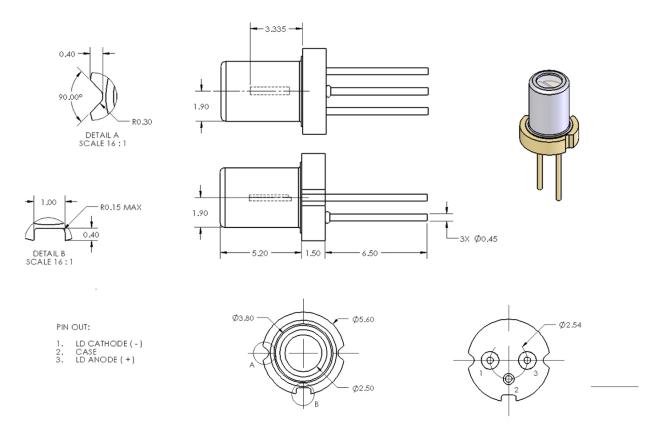




| | Symbol | TO56x-265 | Units |
|---------------------------|-----------------|-----------|--------------|
| Optical | | | |
| Vavelength | λ _c | 1550 | nm (±20) |
| Dutput Power (<10ns) | P° | 50.00 | watts (±10%) |
| Dutput Power (150ns) | P• | 35.00 | watts (±10%) |
| Cavity Length (typ.) | CL | 2500 | μm |
| lo. of Junctions | | 3 | |
| mitter Width | W | 95 | μm |
| mitter Height | Н | 10 | μm |
| Operating Current (<10ns) | I _{op} | 50 | A |
| perating Current (150ns) | I _{op} | 40 | A |
| perating Voltage | V _{op} | 12 | V |
| hreshold Current | I _{th} | 2 | A |
| pecifications | | | |
| pectral Width | δλ | 22 | nm 3dB |
| ast Axis Div. | O_perp | 28 | deg FWHM |
| low Axis Div. | O_parallel | 12 | deg FWHM |
| ulse Width | PW | 150 | ns |
| uty Cycle | DC | 0.1 | % |
| lechanical | | | |
| /eight | | 0.5 | g |
| perating Temp.** | | -40 to 85 | C° |
| itorage Temp. | | -40 to 85 | °C |

**Specified operating conditions are based on 20C heat sink temperature. High temperature operation will reduce performance and MTTF. Unless otherwise indicated all values are nominal. All TO56 products are capped. Capped TO56 specifications assume heatsinking only on flat surface where pins extend.





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DANGER LE / INVISIBLE LASER RADIAT CLASS IIIb and IV LASER PRODUCTS s product complies with 21CFR1040 as applicab er aperture is on the test station. Laser radiation this product is considered an auch Pazard to b This Lase from skin

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